## UNIVERSITY OF CALIFORNIA AT BERKELEY College of Engineering Department of Electrical Engineering and Computer Science

R.W. Brodersen	Midterm Exam (3/11/04)	EECS 140 Spring 2004
Name:	SID:	
-Show your work. -Make approximations to be within 10%. -Write your answers on this page for <u>5 points</u> .		
Use the following parameters:		
-Assume all (W/L)=2, unless otherw -Kn'=Kp'= $10^{-4}$ A/V <sup>2</sup> - $\lambda$ n= $\lambda$ p=0.01 - $\gamma$ =0.2 V <sup>1/2</sup> - $2\Phi_{f}$ =0.6 V -Vto,n=Vto,p=0.3 V	vise shown in the circuit as	
-Assume all substrates tied to appropriate supply unless otherwise shown in the circuit.		

\_



a) What is Vin to set Vout=0?



a) What is the maximum voltage at Vout if  $-1V \le Vin \le 1V$  and all transistors remain in saturation region?

b) Assume Vin is set so that Vout=0 V, what is the DC power dissipation of this circuit?



a) What is the maximum output voltage, Vout?

b) If Iout =  $10 \mu A$ , what is Rout?



Assume the DC voltage at Vout is 0 V:

a) What is 
$$Gm = \frac{l_{out}}{v_{in}} \Big|_{Vout=0}$$
 ?

b) What is Rout?



a) What is  $\frac{v_{out}}{vin}$  if VIN = 0.4 V?

b) What is the minimum value of VIN that has all the transistors in saturation?



b) What is the gain 
$$\frac{vout}{v_1 - v_2}$$
?